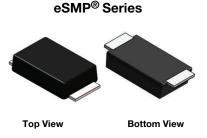
www.vishay.com

VS-3EYH01HM3, VS-3EYH02HM3

Vishay Semiconductors



Hyperfast Rectifier, 3 A FRED Pt®



SlimSMAW (DO-221AD)

Cathode Anode

O

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	3 A				
V _R	100 V, 200 V				
V _F at I _F	0.71 V				
I _{FSM}	70 A				
t _{rr} (typ.)	16 ns				
T _J max.	175 °C				
Package	SlimSMAW (DO-221AD)				
Circuit configuration	Single				

FEATURES

- Low profile package
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

MECHANICAL DATA

Case: SlimSMAW (DO-221AD) Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage			100	V			
VS-3EYH02HM3	V _{RRM}		200	v			
Average rectified forward current	I _{F(AV)} ⁽¹⁾	T _C = 137 °C	3	A			
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 10 ms sine pulse wave	70				
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

Note

⁽¹⁾ Mounted on infinite heatsink

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking	VS-3EYH01HM3	V _{BR} , V _R	- I _B = 100 μA	100	-	-	v	
voltage	VS-3EYH02HM3		$I_R = 100 \mu A$	200	-	-		
Forward voltage, per diode		V _F	I _F = 3 A	-	0.86	0.95		
			I _F = 3 A, T _J = 150 °C	-	0.71	0.79		
Reverse leakage current, per diode		I _R	$V_{R} = V_{R}$ rated	-	-	2		
			$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	20	μA	
Junction capacitance		CT	V _R = 200 V	-	16	-	pF	

Revision: 28-Jan-2021

1

Document Number: 96384

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

RoHS COMPLIANT HALOGEN

FREE

AUTOMOTIVE

VS-3EYH01HM3, VS-3EYH02HM3



www.vishay.com

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/μs, V _R = 30 V	-	22	-	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	100 A/ μ s, V _R = 30 V	-	16	-	
Reverse recovery time	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{A}, I_{rr} = 0.25 \text{ A}$		-	-	30	ns
		T _J = 25 °C		-	18	-	-
		T _J = 125 °C	I _F = 3 A, dI _F /dt = 200 A/μs, V _R = 100 V	-	30	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	2.5	-	A
reak recovery current		T _J = 125 °C		-	4	-	
	Q _{rr}	T _J = 25 °C		-	23	-	nC
Reverse recovery charge		T _J = 125 °C		-	60	-	

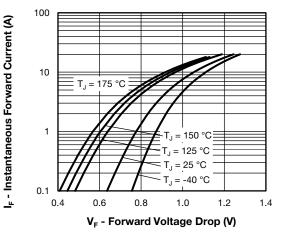
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage	temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾	Infinite heatsink	-	12	15		
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W	
VS-3EYH01HM3					3H1			
Marking device	VS-3EYH02HM3		Case style SlimSMAW (DO-221AD)	3H2				

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC[®] 51-14 transient dual interface test method (TDIM)



Vishay Semiconductors



www.vishay.com

Fig. 1 - Typical Forward Voltage Drop Characteristics

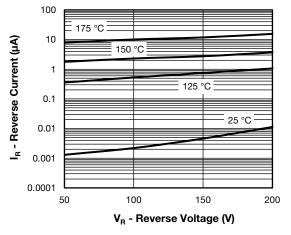


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

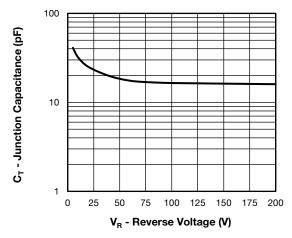


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

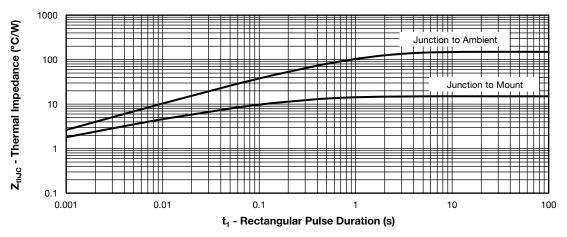
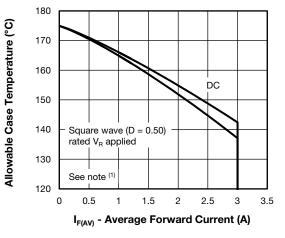


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

Revision: 28-Jan-2021 3 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-3EYH01HM3, VS-3EYH02HM3

Vishay Semiconductors



www.vishay.com

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

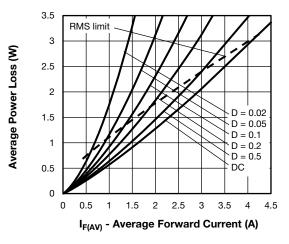


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

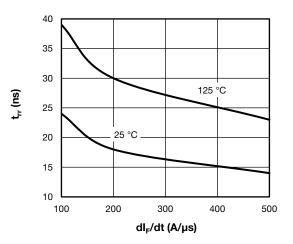


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

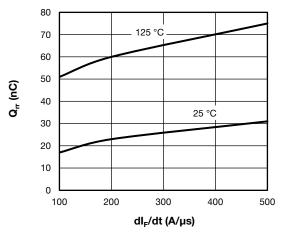


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Revision: 28-Jan-2021 Document Number: 96384 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-3EYH01HM3, VS-3EYH02HM3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	vs-	3	Е	Y	н	02	Н	М3
	1	2	3	4	5	6	7	8
	1 · 2 ·		•	niconduo ng (3 = 3		oduct		
	3 -		uit conf single c	iguratior	ו:			
	4 -		•	IAW (DC	D-221AI	D)		
	5 -		cess typ	-				
	6 - 7 -	Volt	age coo	ist recov de (02 = 101 qua	200 V)			
	8 -			en-free,		complia	nt, and	termina

ORDERING INFORMATION (Example)									
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-3EYH01HM3/H	0.033	Н	3500	7"diameter plastic tape and reel					
VS-3EYH01HM3/I	0.033	I	14 000	13"diameter plastic tape and reel					
VS-3EYH02HM3/H	0.033	Н	3500	7"diameter plastic tape and reel					
VS-3EYH02HM3/I	0.033	1	14 000	13"diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96582				
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96586				



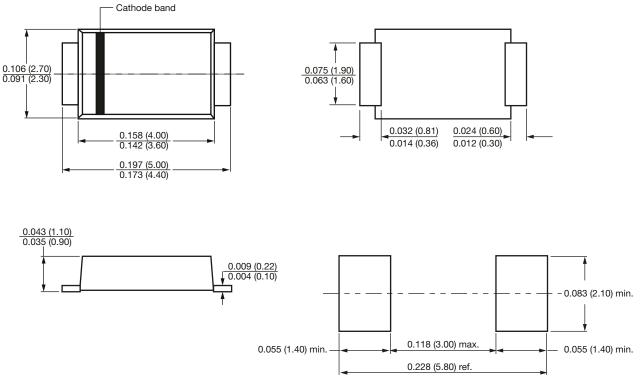
Outline Dimensions

Vishay Semiconductors

SlimSMAW (DO-221AD)

DIMENSIONS in inches (millimeters)

SlimSMAW (DO-221AD)



Mounting pad layout





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)